Spin Splitting and Spin Current in Strained Bulk Sem iconductors

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W e present a theory for two recent experiments in bulk strained sem iconductors [1, 2] and show that a new, previously overboked, strain spin-orbit coupling term may play a fundamental role. We propose simple experiments that could clarify the origin of strain-induced spin-orbit coupling terms in inversion asymmetric sem iconductors. We predict that a uniform magnetization parallel to the electric eld will be induced in the samples studied in [1, 2] for speci c directions of the applied electric eld. We also propose special geometries to detect spin currents in strained sem iconductors.

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Spin manipulation in sem iconductors has seen remarkable theoretical and experim ental interest in recent years with the advent of spin-electronics and with the realization that strong spin-orbit coupling in certain materials can in uence the transport of carriers in so-called spintronics devices [3]. In particular, the issue of creating spin polarization of carriers in nonm agnetic sem iconductors with spin-orbit coupling using only electric elds has caused a urry of theoretical and experim ental activity [4, 5, 6, 7, 8, 9, 10, 11, 12, 13, 14, 15, 16]. Two kinds of theories of spin-polarization under the action of an electric eld have been put forward. The rst kind, dating back since the m id 1980's [9], predicts the existence of a spatially hom ogeneous net spin polarization perpendicular to the applied electric current in two dimensional samples with spin-orbit interaction. This e ect is dissipative and has been recently observed experim entally [17]. There also exist two very recent [4, 5] theories predicting non-dissipative, intrinsic spin currents with the spin polarization and ow direction perpendicular to each other and to the electric eld. This e ect does not create a bulk magnetization but, if observed, can be used for spin in jection, and its validity is being experim entally tested at the present time. One of the theories [5] predicts a spin current polarized out of plane and owing perpendicular to the in-plane electric eld applied on a 2-dimensional sem iconductor sample exhibiting Rashba spin-orbit coupling. As long as the Rashba spin splitting is large enough, the spin conductivity is 'universal' (e=8 ~) in the sense that it does not depend on the value of the coupling. The other e ect [4] appears in the valence band of the bulk sam ples and is proportional to the spin-orbit splitting of the valence bands (to the di erence between the Ferm im om enta of the heavy and light-hole bands).

In the st part of this letter we analyze the theory behind two recent experiments in bulk strained sem iconductors [1, 2] where an electric-eld-induced uniform hom ogeneous spin polarization upon an applied electric eld is observed. We make the case that the observed spinsplitting (whose origin is puzzling) and spin polarization is due to a previously overlooked strain-spin-splitting term , and propose easy experim ental checks of our theory.

In the second part of this letter we predict the appearance of an intrinsic spin polarized spin current in n-doped bulk (and 2 dim ensional) strained sem iconductors (G aA s, G aSb, InSb, InG aA s, A IG aA S, etc) under the in uence of an electric eld. The spin conductance is 'universal', in the sense that it does not depend on the value of strain (for large enough strain), but it is proportional to the average Ferm im om entum of the conduction band. The e ect is due to the spin-orbit splitting of the conduction band under strain and is hence absent in strain-free sem iconductors. The very long spin relaxation time in the conduction band as well as the relative penetration of strain engineering in sem iconductor industry applications make this e ect of potential technological im portance. W e propose an experim ental technique using the already existing setup in [1, 2] to measure the spin current and to di erentiate between the intrinsic spin current and the uniform magnetization e ects.

In [1] nine samples of n-doped (n = $3 10^{16}$ cm 3) In_xGa_1 , As (x = 5%) 7%) of thicknesses between 1500nm, grown in the [001] direction on un-200nm doped GaAs substrate, are used to probe the electron spin dynam ics through time and spatially resolved Faraday rotation (FR). The length and width of the sam ples 80 m. The lattice m ism atch proare roughly 300 m vides for diagonal strain in the x; y; z = [100]; [010]; [001] directions of 0:04% 0:46% [18] (contrary to claim s in [31], the lattice constants in x and y directions are also strained, this being a generic feature of [001] growth). Moreover, anisotropic shear strain develops in all directions (xy;xz;yz = [110]; [101]; [011]) due to di erent direction-dependent strain relaxation rates at the grow th tem perature of around 500C [19]. This guarantees that all the components of the strain tensor $i_j; i_j = x_j y_j z_j$ are non-zero and of the same order of magnitude. The m agnitude of the strain com ponents is given in Table[1].

Pump-probe FR beams measure the total magnetization of the optically injected electron spins in the growth direction z when the samples are placed in an electric eld on the [110] and [110] directions, respectively. The dynamics of the spin packet is mainly described by a precession around a total magnetic eld $B_{tot} = B_{int} + B_{ext}$ where B_{ext} is an externally applied magnetic eld whereas B_{int} is the momentum dependent internal magnetic eld caused by the spin-orbit coupling. The precession around a B_{int} is the main feature of most of the spintronics devices, starting with the Das-Datta spin-eld transistor [22]. Under an applied electric

eld, the average particle m om entum acquires a non-zero value, parallel to the electric eld. The internal magnetic

eld is caused by the spin orbit coupling: the electric eld acts on the particle m om entum which in turn couples to the spin. The signal at the probe beam can be tted to $\cos(g_B \not B_{int} + \not B_{ext} j t = \sim)$ where $_B$ is the Bohrm agneton, g is the electron g-factor while t is the temporal delay between the pump and probe pulses. This t gives the direction and value of \vec{B}_{int} which turns out to be perpendicular to the applied electric eld E and the z axis (for E in-plane); the value of \vec{B}_{int} is used to determ ine the spin splitting $_0 = g_{BB} B_{int}$ and a phenom enological relation $_0 = v_d$ is observed where v_d is the spin-drift velocity and is a constant of proportionality that is the focus of the experiment [1]. Experiments nd that v_d is linearly proportional to the electric eld E.

As a rst step, let us theoretically address the question of origin of . By group theory, inversion symmetry breaking bulk strained sem iconductors exhibit three main types of spin splitting [23]:

$$H = \frac{2}{2m}k^{2} + H_{1} + H_{2} + H_{3};$$

$$H_{1} = \begin{bmatrix} x k_{x} (k_{y}^{2} + k_{z}^{2}) + y k_{y} (k_{z}^{2} + k_{x}^{2}) + z k_{z} (k_{x}^{2} + k_{y}^{2}) \end{bmatrix}$$

$$H_{2} = \frac{1}{2}C_{3}\begin{bmatrix} x (x_{y}k_{y} + x_{z}k_{z}) + y (y_{z}k_{z} + y k_{x}) + z k_{z} (x_{z} + k_{y}) \end{bmatrix}$$

$$H_{3} = D\begin{bmatrix} x k_{x} (z_{z} + y) + y k_{y} (x_{x} + z) + z k_{z} (y_{y} + x) \end{bmatrix}$$

$$(1)$$

 $m = 0.0665m_0$ is the electron m ass in the conduction band [24], ;C₃;D > 0 are m aterial constants, $x_{iy;z}$ are the 3 spin-Paulim atrices, and i_{j} ; $i_{j} = x_{i}y_{i}z$ are the components of the symmetric strain tensor.

All three H am iltonians can be written as the coupling of a ctitious k-dependent internal magnetic eldB^{int} to the electron spin, B^{int}(k)~ = B_x(k) _x + B_y(k) _y + B_z(k) _z (an overall factor of g_B has been absorbed into the de nition of B to sim plify notation). The directions of B^{int} as dependent on the directions of K are shown in Fig[1]. The SIA-type term gives a B^{int} that keeps its orientation as K (jF) is rotated between the [110] and [110] directions, while both B IA-type B^{int} com ing from H₁ and H₃ change their sign between [110] and [110]. The di erence between H₁ and H₃ is that the latter has a nite B^{int} when E jk; y whereas the form er has zero B_{int} for the sam e directions.

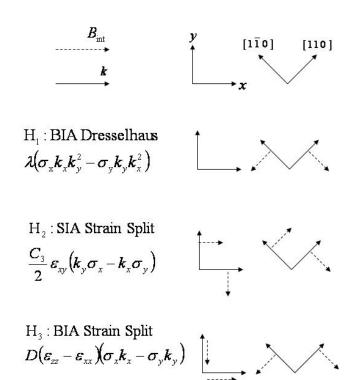


FIG.1: D inection of the internal magnetic eld B_{int} for the three spin splitting H am iltonians H₁;H₂;H₃, (;C₃;D > 0) considering the electric eld E (and hence the average momentum) to be in plane. It was also assumed that $_{xx} = _{yy}$, as appropriate in the experiment [1]. The experimental SIA data cannot be explained by the term H₂, but nevertheless, the SIA type B_{int} seen in the experiment has the same direction as the one plotted here. When E jx or E jy, the BIA term H₃ induces a B_{int} jE whereas the BIA term H₁ does not induce spin splitting for these directions. This constitutes a simple check of the experiment

In [1] the values of the splitting are measured on the [110] and [110] directions and because of the signchanging properties of B_{int} mentioned above, the B IA and the SIA contributions to can be obtained as follows: $B_{IA} = (_{[110]} _{[110]})=2; S_{IA} = (_{[110]} + _{[110]})=2.$ Surprisingly, the spin splitting is more of a B IA -type rather than an SIA -type, contradicting the conventional know ledge that an SIA -type term described by H₂ is responsible for spin splitting in strained sem iconductors [23, 25, 26, 27, 28, 29].

Theoretically, the D resselhaus term H_1 is a bulkinversion asymmetry term that appears even in the absence of strain. As observed in the experiment, the ctitious internal magnetic eldB_{int} is perpendicular to the momentum $\mathcal{K}: \mathcal{B}_{int}(\mathcal{K})\mathcal{K} = 0$, where $B_x = k_x (k_y^2 - k_z^2)$, B_y and B_z being obtained by cubic permutation. For $G = 22 \text{eV} \text{A}^3$. However, we believe this term is not responsible for the spin splitting observed in the experiment [1]. The observed splitting is linear in momentum k, inconsistent with the $H_1 = k^3$. Experiments performed on InSb [29], another material with inversion asymmetry, support this conclusion and point strongly to the fact that strained InSb is described by H_2 . In [29] stress of up to 4 kbar is applied mechanically on a 1 1 10m m³ sample and Shubnikov-de-Haas oscilations are used to probe the band structure. W ithout applied strain, the conduction band exhibits a spin-splitting that is small and cubic in k, described by H_1 . In [29] the application of diagonal does not induce any observable spin splitting whereas the application of shear strain induces a splitting linear in k, described by H2. Relatively large stress-induced splitting of the Ferm i surfaces occurs in the lower concentration (n = 1:4)10¹⁵ 2:0 10¹⁷ cm ³) samples [29]. The energy splitting dispersion switches from k³ in the unstrained case to k when strain (stress) above 1kbar is applied, in accordance to H $_2$ becoming dominant over H $_1$. From a theoretical estimate, at $n = 3 \quad 10^{16}$ cm 3 , H₁ should be of the same size as H_3 and roughly one order of magnitude lower than H_2 . The spin splitting at the Ferm i wavevector $k_F = 0.96 \quad 10^8 \text{m}^{-1}$ due to H₁ is less than 10 ${}^{5}\text{eV}$. By contrast the spin splitting due to H $_{2}$ is $C_{3 xy}k_F = 5.06$ 10² xyeV = 5 10⁵ 15 10⁵ eV for $x_y = 0.1\%$ 0.3% as in [1] (see Table [1] for conversion of strain components from [1] to the orthogonal system _{xv}). An experimental value of C₃=~ = 8 10^5 m =s for GaAswasused [30]. Contrary to previous remarks [31], there is hence no theoretical or experim ental a-priori reason to disregard the strain-dependent spin splitting term s in favor of the D resselhaus k³ term for the doping values in the experiment [1].

There are a number of experimental reasons in [1] hinting the marginal signicance of the k^3 term. In [1] strain plays a critical role in generating the spin-orbit coupling B_{int} . Samples prepared from the same wafer but unstrained show a reduction by an order of magnitude of B_{int} along both the [110] and the [110] directions. If H_1 were responsible for spin splitting, its value would remain unchanged upon varying strain. Strain could only enter the system through the variation of the electron mass in the x;y;z directions, as [31] points out. How ever, these variations with strain are of a maximum 2% 3% [24, 31] thereby not accounting for the order of magnitude variation of the spin-splitting between the strained and the unstrained cases observed in [1].

The term H_2 is a structural inversion asymmetry (SIA)-type term that has its origin in the acoustic phonon interaction of the valence band with the conduction band [23]. In the fram ework of the K ane's 8 8 m atrix (2 2 for the conduction and split-o band and 4 4 for the valence band) the conduction band couples to the valence band. In system s with inversion symmetry where

the selection rules for L are satis ed, it is impossible to couple spin-0 ('jsi) with spin-1 ('jzi) through a spin-2 term ($_{ij}$) and hence $hsj_{xy}jzi = 0$. However, when inversion symmetry is broken, the fore-mentioned term need not be zero as the L selection rule need not apply. Upon straining, the matrix elements between the conduction and valence band have the form hsjxy jzi (plus cyclic permutations) where jsi is the s-orbital and jzi is one of the p orbitals. Through perturbation theory, one can compute the e ect of this valence-conduction band interaction when projected to the conduction band and obtain the conduction band e ective Ham iltonian H₂ [23, 26, 27, 28]. Taking into account that the electric eld is in-plane (< k_z >= 0) and that $xy \in 0$ (see Table[1]), in H_2 the components of the internal magnetic eld (which due to the rescaling by g_B has units of energy) are: $B_x = \frac{1}{2}C_{3xy}k_y$; $B_y = \frac{1}{2}C_{3yx}k_x =$ $\frac{1}{2}C_{3} x_{y}k_{x}$. Switching coordinates to the [110] and [110]

directions, B $_{[110]} = \frac{1}{2}C_3 \times k_{[110]}$; B $_{[110]} = \frac{1}{2}C_3 \times k_{[110]}$ (see Fig[1]. Since H₂ is an SIA term, the spin splitting

will be of SIA type $_{\text{SIA}}^{\text{th}}$ (th stands for the theoretical estimate). Since $< k > = \frac{1}{2}m v_d$ where v_d is the drift velocity of the spin packed due to the electric eld, we get a simple form ula for the

$$_{\text{SIA}}^{\text{th}} = \frac{C_3}{\sim} _{\text{xy}} m$$
 (2)

By using the experimentally known value for $C_3 = 8~10^5 \text{m}$ =2, the predicted values for $^{\rm th}_{\rm SIA}$ are given in Table I. The theoretical values are larger than the observed ones by a factor of 3 30 and no m atching trend between the data and the SIA term H_2 can be found. M oreover, as remarked in [1] no system atic correlation between the experim entally observed SIA contribution and the strain is observed. We hence come to the conclusion that the SIA spin splitting observed in [1] is not induced by the uniform shear strain (which would give the values the sing and which have been con immed in mechanical experiments) but borrows substantially from the dislocations and strain gradient inherent in growing such a thick sample through MBE techniques. This is not to say that the SIA term is negligible: as seen in Table I the SIA term is substantial and comparable in magnitude with the BIA term . However, the SIA term does not correlate with strain ad cannot be described by H $_2$.

The remaining spin splitting term is H₃. Although this term is allowed by group theory, it only shows up at higher order in perturbation theory than H₂ in the k p method. We claim that in the experiment [1] this term is responsible for the spin-splitting observed, and determ ine the value of the constant D. We note, how-ever, that this does not settle the theoretical puzzle of why the H₃ would be more signi cant than H₂ in this case, which might have to do with the conditions of the experiment such as low temperature, the appearance of dislocations and strain gradient. H₃ is a Ham il-

Sample	ZZ	_{хх} = _{уу}	хy	exp SIA	th SIA	exp B IA	exp BIA ZZ XX	D =~
А	0.46	-0.16	0.2	-24	604	75	121	1.59
В	0.14	-0.2	80.0	-26	241	13	38	0.5
Е	0.13	-0.42	0.18	69	543	43	78	1.03
F	0.07	-0.32	0.12	54	362	31	79	1.04
G	0.04	-0.32	-0.04	44	-121	31	86	1.13
Н	0.13	-0.42	0.26	-2	785	24	43	0.56
I	0.04	-0.16	0.2	65	604	23	115	1.51

TABLE I: Strain components (in %) in [1] converted to cartesian coordinates (C and D are compositionally graded lm s [1]). The conversion equations, obtained after a sim ple coordinate transform ation, are: zz = [001]; xx = yy = $\frac{1}{2} (110) + 110); xy = \frac{1}{2} (110) \quad \text{(110)}. The m easured spin splitting slope values exp and exp as well as the theoret$ ical value $\frac{\text{th}}{\text{SIA}}$ obtained using the Ham iltonians H $_2$ for the SIA - type splitting are given in neV nS m⁻¹, the units of [1]. The value of the deform ation potential D in the term H₃, determ ined as explained in Eq(4) is given for each sam ple. The discrepancies between the values of $\frac{exp}{SIA}$ and $\frac{th}{SIA}$ make the case that H $_2$ is not the full mechanism for strain SIA splitting. For ve (A, E, F, G, I) out of the seven sam ples the values of the deform ation potential D deduced from the H $_3$ model of the strain BIA splitting are within 30% of each other. Combined with the simplicity of the model, this match gives weight to the suggestion that BIA splitting is produced by a B IA term . $e_{B IA}^{exp} = (z_{zz} x_{xx})$ is measured in 10^2 neV nS m⁻¹, while D is measured in 10^4 m =s

tonian of BIA -type and vanishes with vanishing strain, thereby satisfying two of the experim ental observations in [1]. From Eq.[1], the internal magnetic eldB_{int} reads: $_{yy}$); $B_y = D k_y (xx)$ $B_x = D k_x (z_z)$ $_{xx}$); $B_z =$ $_{xx}$), and since the in-plane electric eld in- $D k_z (vv)$ uences only the in-plane momentum, $\langle k_z \rangle = 0$ and only the two in-plane components of the internal magnetic eld rem ain. In accordance with the experim ent, we place xx = yy, and zz = xx > 0 (Table[I]). We hence have $B_x = k_x D$ ($_{zz}$ $_{xx}$); $B_y = k_y D$ ($_{xx}$ zz), D $(z_z x_x) > 0$. Since B_{int} is not perpendicular to kjE: $B_x k_x + B_y k_y = (k_x^2 - k_y^2)D$ (zz $_{xx}$), one may think this term is incompatible with the observed B_{int} ? E jk in [1]. This, however, would be hasty: the experiment is performed in only two directions, with E jj[110] and E jj[110], for which $k_x = k_y$. For these two directions only, the B_{int} in H_3 is perpendicular to the momentum and the electric eld, hence satisfying a major constraint the experimental data poses on the theory. Since the value of the constant D is unknown from previous experim ental studies (although it was suggested that they can be som etim es sizable [32]) there is no way of theoretically predicting the values of the spin-splitting from ourm odel. However, we can check if the model is consistent with the experimental data and we can also obtain a value of the constant D which, being a material constant, should be similar on all the samples cited here. Since $\langle k \rangle = \frac{m}{2} v_d$

where v_d is the spin drift velocity along the spin packet we nd:

$$^{h}_{B \text{ IA]}} = 2 \frac{D}{\sim} (_{zz} \qquad _{xx}) m \qquad (3)$$

We can determ ine the value of D from the experimental data for and strain :

$$\frac{D}{\sim} = \frac{1}{2m} \frac{\exp}{\left[\beta \text{ IA}\right]}$$
(4)

As a consistency check, since D is a material constant, exp [B IA]=(zz xx) should be quasi-constant between the samples quoted in the experiment. In 5 out of the 7 samples studied in [1], the values of $\frac{\exp}{[B IA]} = (zz)$ _{xx}) are close together to within 30%, lum ped in two groups (samples A; I are very close to each other, and within 30% of the value for E; F; G which are again very close between them selves). The sam ples E ;F;G were grown in the same day. The deviant samples B; H were also grown in the same day, and hence the variation of the constant coe cient D within a sample set that was grown on the same day is less than 15% [21]. Di erent growth conditions are most likely responsible for the (still sm all) variations between sam ples grown in di erent days. The consistency check is further proof that H₃ is the term responsible to the spin-splitting in [1]. The values obtained for D are given in Table [I].

We showed that H₃ is a BIA -type Ham iltonian vanishing with vanishing strain, with an internal magnetic eld that is perpendicular to the applied electric eld for the two experim ental directions [110] and [110] and which is consistent with the reported data for the spin splitting. On the other hand, H_1 and H_2 , the previously known spin splitting terms, fail to reproduce the data on more than several counts. It is easy to experim entally prove, using the setup in [1], that H_3 is responsible for the spin splitting is easy: one would measure the internal magnetic eld due to BIA on the x or y direction. In this case, an H₃ term would give an internal magnetic eld parallel to \mathbf{E} (of course, there will also be an internal \mathbf{B} from an SIA term that is still perpendicular to \vec{E} , but a component of Bint parallel to the electric eld should be easily detectable).

In another beautiful experiment, K ato et al. measure through Farraday Rotation (FR) a nonzero uniform magnetization el induced by driving an electric current (electric eld) through the sam ple E of their previous experiment [1]. It has been long predicted [9, 10] that sem iconductors with spin-orbit coupling will exhibit a uniform magnetization when placed in an electric eld generating a charge current. This can be trivially understood by a sim ple argument: writing the spin-orbit H am iltonian as a K dependent magnetic eld Zeem an coupled to spin, $B_{int}(k)\sim (k)$, the application of an electric eld E will make the average value of the momentum be non-zero $\langle \tilde{\kappa} \rangle = \frac{e}{m} E'$ where is the momentum relaxation time. This creates a non-zero average $\langle \tilde{B}_{int} \rangle = \tilde{B} (\langle \tilde{\kappa} \rangle)$ which orients the spins along its direction through the Zeem an-like coupling of the spin-orbit term.

We now try to numerically estimate the value of the uniform magnetization $_{el}$ using the BIA -type H₃. From [2], the BIA contribution to the uniform magnetization can be obtained as $_{el}^{BIA} = \frac{1}{2} \begin{pmatrix} F & jj[10] \\ el \end{pmatrix}$ and is around 3 10^{18} m³ for E = 10^4 V=m . We will now try to estimate this from rst principles using H₃ as the main BIA term and using the value of D for sample E deduced in Table[I]. A simple linear response calculation of the magnetization $_i$ to the electric current J_j (due to the applied electric eld E_j) gives:

$$Q_{ij} = hT_{i}J_{j}i = \begin{bmatrix} \frac{1}{e_{1}} & \frac{2}{e_{1}} & Q_{ij}E_{j} \\ \frac{1}{e_{1}} & \frac{$$

where i; j = x; y; z and B_i(k) are the components of the internal magnetic eld for H₃, B = $\frac{1}{1 = x, y; z} B_i B_i$, n_E is the Ferm i function of the spin-split energies E = $\frac{2^2}{2m} k^2$ B for H₃. For the H am iltonian H₃, considering xx = yy we obtain for:

$$_{\text{el}}^{\text{B IA}} = \frac{\text{e m } k_{\text{F}} \text{ D } (_{zz} \quad _{yy})}{^{3}} \text{E}$$
(6)

(5)

As previously pointed out the magnetization is parallel to the electric eld for E jp? or E jp?. This provides an important and easy check of the above assumption that the observed strain spin splitting comes from H₃. The only two directions where \sim_{el} is perpendicular to the electric eld are [110] and [110], the directions on which the experiment is performed. Considering a sample of mobility = 0:6m²=V s [18] we obtain an estimate for $el = 3:45 \ 10^{18} \text{m}^{-3}$ for a eld E = 10^4V =m, compared to an experimental value of 3 10^{18}m^{-3} for the same value of the electric eld. The theoretical value obtained is within the experiment's error margins.

Finally, using the current setup in [1, 2] we propose an experiment to test the prediction of dissipationless spin current. For spin 1/2 two-dimensional systems, the initial prediction [5] is subject to some sort of controversy, [14, 33, 34] as the introduction of impurities apparently makes the spin current vanish. We here adopt the alternative view and propose a clear-cut experiment which can see the spin accumulation due to the spin current. Similar to the 2D case, in the present case, the application of an electric eld E_j to a semiconductor with spin orbit coupling will create a spin current S_1^i owing perpendicular to the electric eld and polarized perpendicular to both the eld and the direction of ow. U sing

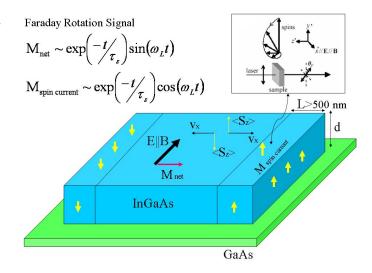


FIG.2: An electric eld will cause both an observed net uniform bulk magnetization and a proposed spin current. The spin current will accumulate at the edges over a spin di usion length of more than 500nm thus making its detection practical with a beam slightly more focused than in [2]. The uniform magnetization and the spin current spin accumulatio are =2 out of phase.

linear response, the expression for the spin conductance is:

$$J_{i}^{l} = \frac{1}{ij}E_{j}$$

$$\frac{J_{i}^{l}}{2m} = \frac{\lambda^{2}}{2m} \frac{Z_{i}}{(Z_{i})^{3}} \frac{n_{E}}{B_{i}^{3}} \frac{n_{E_{i}}}{B_{i}^{3}} k_{i} \ln m B_{n} \frac{QB_{m}}{QK_{i}}$$
(7)

where i; j; l;m; n = x; y; z, $_{lnm}$ is the totally antisym – metric tensor in 3 dimensions and $B_{i}(k)$ are the com – ponents of the internal magnetic eld. For H_{3} and for $_{xx} = _{yy}$ the only non-zero components of the spin conductance are:

where ; are the polar angles of k and where k; k_{+} are the ferm in on enta of the two bands. W hen both bands are occupied (positive Ferm ienergy), we nd $k_{-2} = \frac{2m}{k}$; $(k) = D(z_{z} = x_{x})k \sin$. U sually the spin splitting is much an aller than the Ferm ienergy, and we can de ne an average Ferm in on entum $k_{\rm F} = \frac{1}{2}(k + k_{+})$ (3 $^{2}n)^{1=3}$, n being the dopant density. W ith this, we nd that the spin-conductivity will be independent of the value of the strain:

$${}^{3}_{21} = {}^{3}_{12} = \frac{e}{\sim} \frac{k_{\rm f}}{4^{2}}$$
 (9)

The result for the spin conductance is interm ediate between the 2D spin 1/2 spin current and the 3D spin 3/2spin current. Sim ilar to [4] but unlike [5] the spin conductance depends on the ferm im om entum, a characteristic of the 3D. Unlike [4], but sim ilar to [5], the spin conductance does not depend on the strength of spin-orbit coupling. Even though the spin conductance does not depend on the value of strain, it is essential that spin-orbit splitting (due to strain in this case) be present. Upon the application of an electric eld on the x axis, a spin current will ow on the y axis spin polarized in the z direction. For $n = 10^{16}$ cm³, and a eld $E = 10^{4}$ V=m we estim ate a spin current $j_{\rm spin}$ = $\frac{e}{\sim}\frac{k_{\rm f}}{4}E$ = 2 $~10^{21}$ ($_{\rm B}$ =cm 2s) where $_{\rm B}$ is a Bohr magneton. Since spin conductivity varies as $n^{\frac{1}{3}}$ and charge conductivity varies as n_{i} for low values of n the spin conductance will overtake the charge conductance and the spin current will be larger than the charge current caused by the electric eld. The density at which this happens is $n^{2=3} < \frac{2e}{2} \cdot \frac{(6^{-2})^{1=3}}{8^{-2}}$, where is the mobility in the sample, or $n < 2 \quad 10^{16}$ cm 3 for a sample of mobility = $0:6m^2 = V s$.

The ow will result in accumulation on the opposite zx faces of the crystal (see Fig[2]). For the present experim ent, we estim ate this spin accumulation of the order of $J_{spin S} = 10^{13} B = cm^2$. Due to the extremely spin life time of above lns, the distance from the edge of the sam ple, the spin di usion length is very large, of the order L = 500nm 1 m. The FR beam used in [2] has a resolution of 4:7 m = 9:7 m on the x and y axis respectively, but focusing the beam within 1 m is possible [20, 35]. Then, if the spin current prediction is right, applying the FR beam on the edge of the sample should give a clear signal (larger than the uniform magnetization in the bulk). Since the uniform magnetization and the spin accumulation due to spin hall current are perpendicular to each other, in tim e-resolved FR experim ents, the spin current spin accumulation and the uniform magnetization are out of phase by =2 (see F ig [2)

In conclusion, we have analyzed two very recent experim ents [1, 2] and proved that conventional spin splitting terms and strain spin splitting terms do not explain the data. We have introduced a previously largely unknown term and made the case as to why it explains the observed features in [1, 2]. We have proposed further simple experim ents to verify our assertions. If true, our proposal gives rise to the clear possibility of obtaining a uniform m agnetization parallel to the applied electric eld, as opposed to the one perpendicular to it that has been observed so far. A long with predicting a 3D spin current, we have also proposed a way to test the spin currents in spin 1/2system s.

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